

PSMN1R8-40YLC

N-channel 40 V 1.8 m Ω logic level MOSFET in LFPAK using NextPower technology

22 August 2012

Product data sheet

1. Product profile

1.1 General description

Logic level enhancement mode N-channel MOSFET in LFPAK package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High reliability Power SO8 package, qualified to 175°C
- Optimised for 4.5V Gate drive utilising NextPower Superjunction technology
- Ultra low QG, QGD, & QOSS for high system efficiencies at low and high loads
- Ultra low Rdson and low parasitic inductance

1.3 Applications

- DC-to-DC converters
- Load switching
- Power OR-ing
- Server power supplies
- Sync rectifier

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	-	100	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	272	W
T _j	junction temperature			-55	-	175	°C
Static charact	eristics						
Doon	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 12		-	1.8	2.1	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12		_	1.5	1.8	mΩ
Dynamic characteristics							
Q_{GD}	gate-drain charge	V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 20 V; Fig. 15; Fig. 14		-	10.9	-	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 20 V; Fig. 15; Fig. 14	-	45	-	nC

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source		
3	S	source	[d	G 4
4	G	gate	و و و و و	mbb076 S
mb	D	mounting base; connected to drain	1 2 3 4 LFPAK; Power- SO8 (SOT669)	

3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PSMN1R8-40YLC	LFPAK; Power-SO8	plastic single-ended surface-mounted package; 4 leads	SOT669		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	40	V
V_{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	100	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	[1]	-	100	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 4		-	1128	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	272	W
T _{stg}	storage temperature			-55	175	°C
T _j	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C

Symbol	Parameter	Conditions		Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	MM (JEDEC JESD22-A115)		890	-	V
Source-drain	diode					
I _S	source current	T _{mb} = 25 °C	[1]	-	100	Α
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	1128	Α
Avalanche ruggedness						
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 100 A; $V_{sup} \le$ 40 V; R_{GS} = 50 Ω ; unclamped; Fig. 3		-	248	mJ

[1] Continuous current is limited by package.

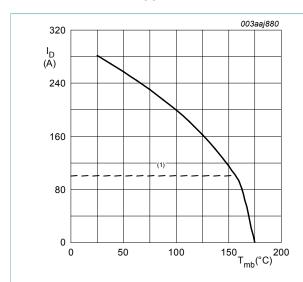


Fig. 1. Continuous drain current as a function of mounting base temperature

 $\label{eq:VGS} V_{\textit{GS}} \! \geq \! 10 \, V$ (1) Capped at 100 A due to package.

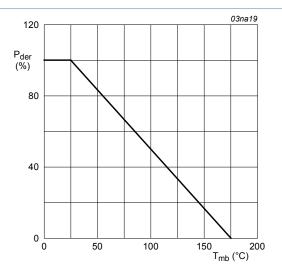


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

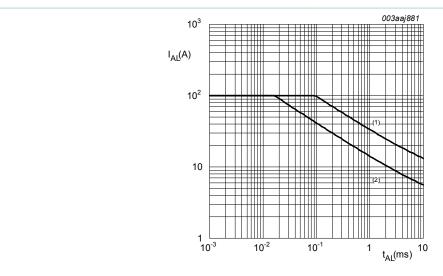
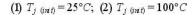


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time



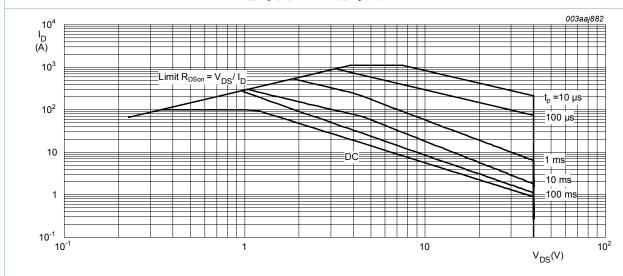


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

$$T_{mb} = 25^{\circ}C$$
; I_{DM} is a single pulse

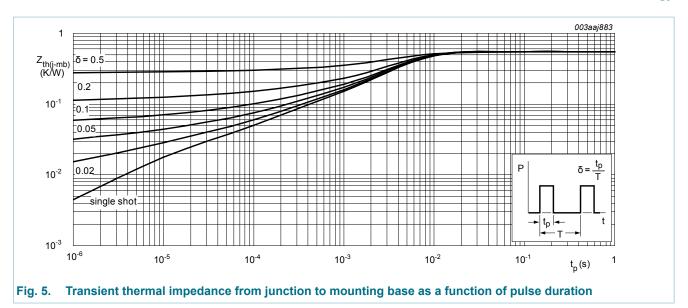
5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.45	0.55	K/W

PSMN1R8-40YLC

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6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		<u> </u>			
V _{(BR)DSS}	drain-source	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 ^{\circ}C$	40	-	-	V
	breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55 °C$	36	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C};$ Fig. 10	1.05	1.45	1.95	V
		I_D = 10 mA; V_{DS} = V_{GS} ; T_j = 150 °C; Fig. 11	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C};$ Fig. 11	-	-	2.25	V
I _{DSS} drain leakage curre	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 40 V; V _{GS} = 0 V; T _j = 150 °C	-	-	100	μΑ
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_{D} = 25 A; T_{j} = 25 °C; Fig. 12	-	1.8	2.1	mΩ
		V _{GS} = 4.5 V; I _D = 25 A; T _j = 150 °C; Fig. 12; Fig. 13	-	-	3.6	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	-	1.5	1.8	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 12; Fig. 13	-	-	3.25	mΩ

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _G	gate resistance	f = 1 MHz		0.5	1	2	Ω
Dynamic ch	naracteristics					1	
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 14; Fig. 15		-	96	-	nC
		I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 15; Fig. 14		-	45	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V		-	88	-	nC
Q _{GS}	gate-source charge	$I_D = 25 \text{ A}; V_{DS} = 20 \text{ V}; V_{GS} = 4.5 \text{ V};$		-	15.5	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 15; Fig. 14		-	8.4	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	7.1	-	nC
Q_{GD}	gate-drain charge			-	10.9	-	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 20 V; <u>Fig. 15</u> ; <u>Fig. 14</u>		-	2.7	-	V
C _{iss}	input capacitance	$V_{DS} = 20 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}; Fig. 16$		-	6680	-	pF
C _{oss}	output capacitance			-	825	-	pF
C _{rss}	reverse transfer capacitance			-	310	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 20 V; R_L = 0.8 Ω ; V_{GS} = 4.5 V;		-	32.2	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	37	-	ns
t _{d(off)}	turn-off delay time			-	62.5	-	ns
t _f	fall time			-	31.7	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	30	-	nC
Source-drai	in diode						
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$		_	0.77	1.1	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	37	-	ns
Q _r	recovered charge	V _{DS} = 20 V		-	43	-	nC
t _a	reverse recovery rise time	$V_{GS} = 0 \text{ V; } I_S = 25 \text{ A; } dI_S/dt = -100 \text{ A/}\mu\text{s;}$ $V_{DS} = 20 \text{ V; } Fig. 18$		-	21	-	ns
t _b	reverse recovery fall time	- 100 - 100		-	16	-	ns

6/14

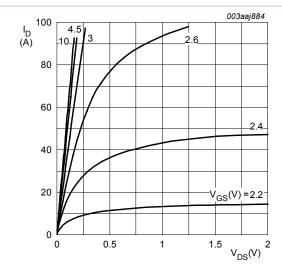


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



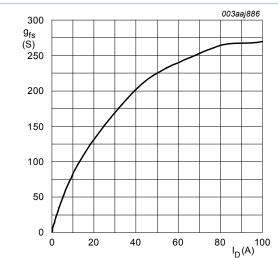


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25$$
°C; $V_{DS} = 10V$

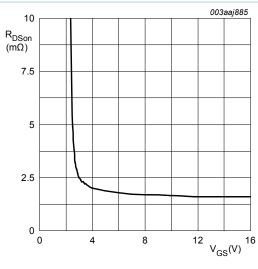


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

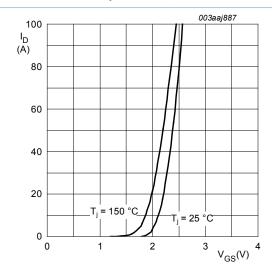


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

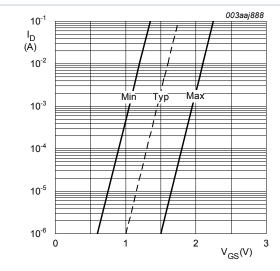
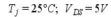


Fig. 10. Sub-threshold drain current as a function of gate-source voltage



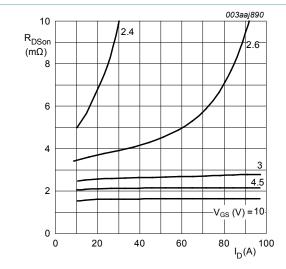


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

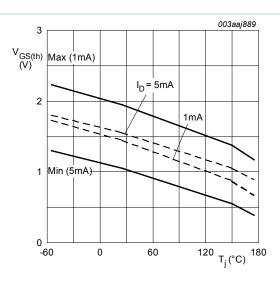


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$$V_{DS} = V_{GS}$$

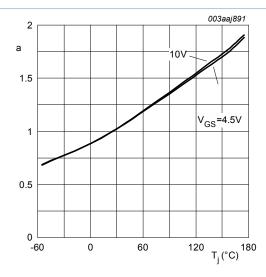


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}}$$

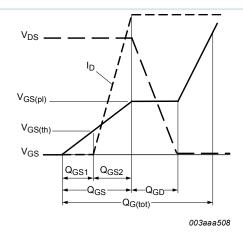


Fig. 14. Gate charge waveform definitions

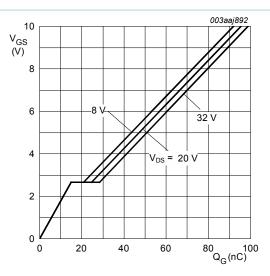


Fig. 15. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 25A$$

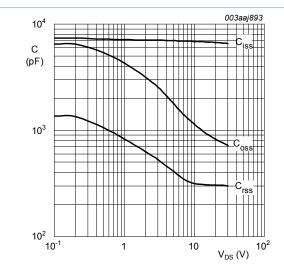


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$

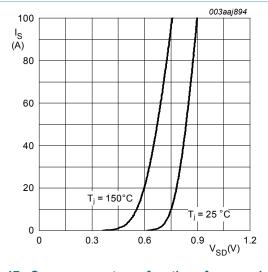
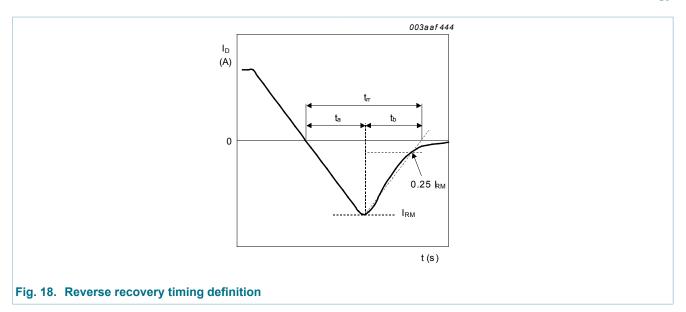


Fig. 17. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$



7. Package outline

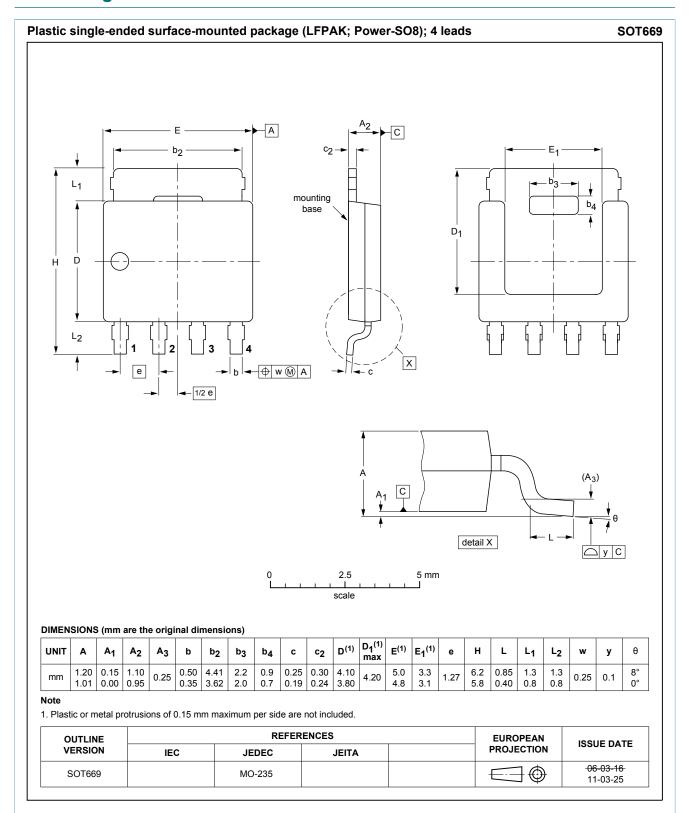


Fig. 19. Package outline LFPAK; Power-SO8 (SOT669)

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9. Contents

1	Product profile	1
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Limiting values	2
5	Thermal characteristics	4
6	Characteristics	5
7	Package outline	11
8	Legal information	12
8.1	Data sheet status	
8.2	Definitions	12
8.3	Disclaimers	12
8.4	Trademarks	13

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